MM74HCT240N Datasheet

DiGi Electronics Part Number	MM74HCT240N-DG
Manufacturer	onsemi
Manufacturer Product Number	MM74HCT240N
Description	IC BUFFER INVERT 5.5V 20DIP
Detailed Description	Buffer, Inverting 2 Element 4 Bit per Element 3-State Output 20-PDIP

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MM74HCT240N	onsemi
Series:	Product Status:
74HCT	Obsolete
Logic Type:	Number of Elements:
Buffer, Inverting	2
Number of Bits per Element:	Input Type:
4	-
Output Type:	Current - Output High, Low:
3-State	7.2mA, 7.2mA
Voltage - Supply:	Operating Temperature:
4.5V ~ 5.5V	-40°C ~ 85°C (TA)
Mounting Type:	Package / Case:
Through Hole	20-DIP (0.300", 7.62mm)
Supplier Device Package:	Base Product Number:
20-PDIP	74HCT240

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8542.39.0001

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DATA SHEET
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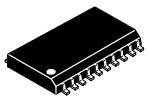
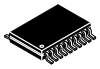
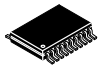
Inverting Octal 3-STATE Buffer, Octal 3-STATE Buffer

MM74HCT240, MM74HCT244


SOIC−20 WB
CASE 751D−05


TSSOP−20 WB
CASE 948E


TSSOP−20
CASE 948AQ

General Description

The MM74HCT240 and MM74HCT244 3−STATE buffers utilize advanced silicon−gate CMOS technology and are general purpose high speed inverting and non−inverting buffers. They possess high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits achieve speeds comparable to low power Schottky devices, while retaining the low power consumption of CMOS. All three devices are TTL input compatible and have a fanout of 15 LS−TTL equivalent inputs.

MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug−in replacements for LS−TTL devices and can be used to reduce power consumption in existing designs.

The MM74HCT240 is an inverting buffer and the MM74HCT244 is a non−inverting buffer. Each device has two active low enables (1G and 2G), and each enable independently controls 4 buffers.

All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Features

- TTL Input Compatible
- Typical Propagation Delay: 14 ns
- 3−STATE Outputs for Connection to System Buses
- Low Quiescent Supply Current: 160 μA
- High Output Drive Current: 6 mA (min)
- These are Pb−Free Devices

TRUTH TABLES

MM74HCT240

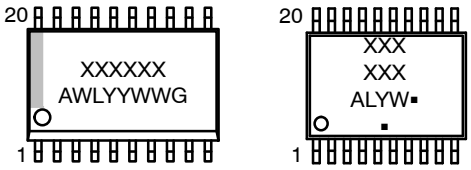
$1\overline{G}$	1A	1Y	$2\overline{G}$	2A	2Y
L	L	H	L	L	H
L	H	L	L	H	L
H	L	Z	H	L	Z
H	H	Z	H	H	Z

MM74HCT244

$1\overline{G}$	1A	1Y	$2\overline{G}$	2A	2Y
L	L	L	L	L	L
L	H	H	L	H	H
H	L	Z	H	L	Z
H	H	Z	H	H	Z

NOTES: H = HIGH Level
L = LOW Level
Z = High Impedance

MARKING DIAGRAMS

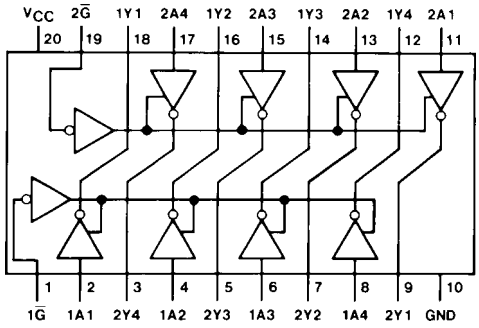


XXXXX = Specific Device Code
A = Assembly Location
L/WL = Wafer Lot
Y/YY = Year
W/WW = Work Week
▪ or G = Pb−Free Package

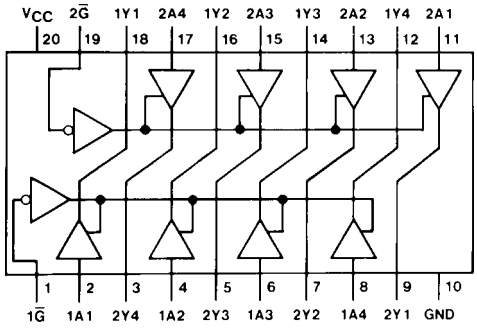
(Note: Microdot may be in either location)

CONNECTION DIAGRAMS

Pin Assignment for SOIC and TSSOP



MM74HCT240 (Top View)



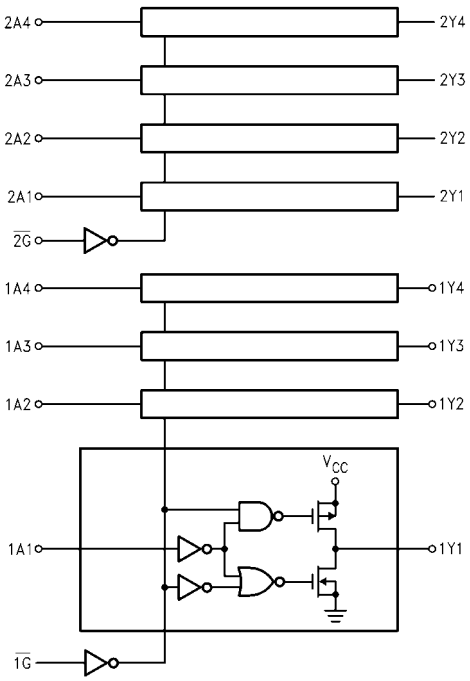
MM74HCT244 (Top View)

ORDERING INFORMATION

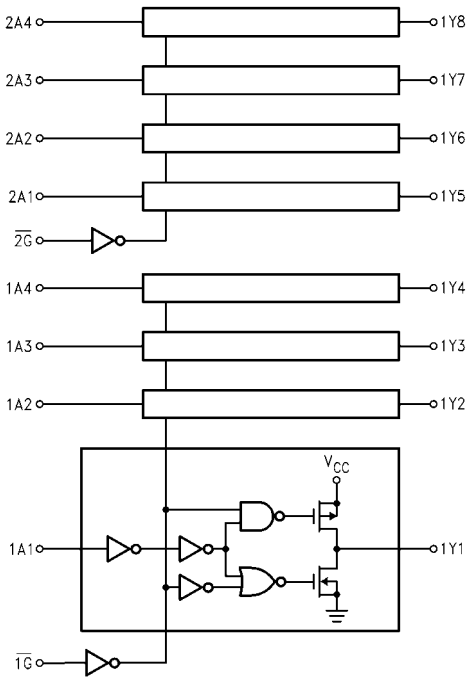
See detailed ordering, marking and shipping information on page 4 of this data sheet.

MM74HCT240, MM74HCT244

Logic Diagrams



MM74HCT240



MM74HCT244

Figure 1. Logic Diagrams

ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	−0.5 to +6.5	V
V_{IN}	DC Input Voltage	−0.5 to V_{CC} + 0.5	V
V_{OUT}	DC Output Voltage	−0.5 to V_{CC} + 0.5	V
I_{IK}, I_{OK}	Clamp Diode Current	±20	mA
I_{OUT}	DC Output Current, per Pin	±35	mA
I_{CC}	DC V_{CC} or GND Current, per Pin	±70	mA
T_{STG}	Storage Temperature Range	−65 to +150	°C
P_D	Power Dissipation SOIC−20W TSSOP−20	 1302 833	mW
T_L	Lead Temperature (Soldering 10 seconds)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Unless otherwise specified all voltages are referenced to ground.

RECOMMENDED OPERATING CONDITIONS (Note 1)

Symbol	Parameter	Min	Max	Unit
V_{CC}	Supply Voltage	4.5	5.5	V
V_{IN}, V_{OUT}	DC Input or Output Voltage	0	V_{CC}	V
T_A	Operating Temperature Range	−55	+125	°C
t_r, t_f	Input Rise or Fall Times	−	500	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (V_{CC} = 5 V ±10% unless otherwise specified)

Symbol	Parameter	Conditions	T_A = 25°C	T_A = −40°C to 85°C	T_A = −55°C to 125°C	Unit
			Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		−	2.0	2.0	2.0	V
V_{IL}	Maximum LOW Level Input Voltage		−	0.8	0.8	0.8	V
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN-EE} = V_{IH} or V_{IL} $\|I_{OUT}\|$ = 20 μA $\|I_{OUT}\|$ = 6.0 mA, V_{CC} = 4.5 V $\|I_{OUT}\|$ = 7.2 mA, V_{CC} = 5.5 V	 V_{CC} 4.2 5.2	 V_{CC}−0.1 3.98 4.98	 V_{CC}−0.1 3.84 4.84	 V_{CC}−0.1 3.7 4.7	V
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL} $\|I_{OUT}\|$ = 20 μA $\|I_{OUT}\|$ = 6.0 mA, V_{CC} = 4.5 V $\|I_{OUT}\|$ = 7.2 mA, V_{CC} = 5.5 V	 0 0.2 0.2	 0.1 0.26 0.26	 0.1 0.33 0.33	 0.1 0.4 0.4	V
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND, V_{IH} or V_{IL}	−	±0.05	±0.5	±1.0	μA
I_{OZ}	Maximum 3−STATE Output Leakage Current	V_{OUT} = V_{CC} or GND $\overline{G}$ = V_{IH} G = V_{IL}	−	±0.25	±2.5	±10	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND I_{OUT} = 0 μA	−	4.0	40	160	μA
		V_{IN} = 2.4 V or 0.5 V (Note 2)	0.6	1.0	1.3	1.5	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Measured per input. All other inputs at V_{CC} or GND.

AC ELECTRICAL CHARACTERISTICS

(MM74HCT240, MM74HCT244 V_{CC} = 5.0 V, $t_r = t_f$ = 6 ns, T_A = 25°C, unless otherwise specified)

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Unit
t_{PHL}, t_{PLH}	Maximum Output Propagation Delay	C_L = 45 pF	14	18	ns
t_{PZL}, t_{PZH}	Maximum Output Enable Time	C_L = 45 pF, R_L = 1 kΩ	20	30	ns
t_{PLZ}, t_{PHZ}	Maximum Output Disable Time	C_L = 5 pF, R_L = 1 kΩ	16	25	ns

AC ELECTRICAL CHARACTERISTICS

(MM74HCT240, MM74HCT244 V_{CC} = 5.0 V ±10%, $t_r = t_f$ = 6 ns, unless otherwise specified)

Symbol	Parameter	Conditions	T_A = 25°C	T_A = −40°C to 85°C		T_A = −55°C to 125°C	Unit
			Typ	Guaranteed Limits			
t_{PHL}, t_{PLH}	Maximum Output Propagation Delay	C_L = 50 pF	14	20	25	30	ns
		C_L = 150 pF	20	28	35	42	
t_{PZH}, t_{PZL}	Maximum Output Enable Time	R_L = 1 kΩ, C_L = 50 pF	21	30	38	45	ns
		R_L = 1 kΩ, C_L = 150 pF	26	42	53	63	ns
t_{PHZ}, t_{PLZ}	Maximum Output Disable Time	R_L = 1 kΩ C_L = 50 pF	16	25	32	38	ns
t_{THL}, t_{TLH}	Maximum Output Rise and Fall Time	C_L = 50 pF	6	12	15	18	ns
C_{IN}	Maximum Input Capacitance		10	15	15	15	pF
C_{OUT}	Maximum Output Capacitance		15	20	20	20	pF
C_{PD}	Power Dissipation Capacitance (Note 3)	(per buffer) $\overline{G}$ = V_{CC}, G = GND $\overline{G}$ = GND, G = V_{CC}	 5 90	 – –	 – –	 – –	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

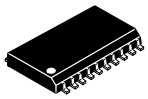
3. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \cdot V_{CC}^2 \cdot f + I_{CC} \cdot V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \cdot V_{CC} \cdot f + I_{CC}$.

ORDERING INFORMATION

Device	Package	Shipping†
MM74HCT240MTCX	TSSOP−20, case 948AQ (Pb−Free)	2500 Units / Tape & Reel
MM74HCT244MTC	TSSOP−20 WB, case 948E (Pb−Free)	75 Units / Tube
MM74HCT244MTCX	TSSOP−20, case 948AQ (Pb−Free)	2500 Units / Tape & Reel
MM74HCT244WM	SOIC−20 WB, case 751D−05 (Pb−Free)	38 Units / Tube
MM74HCT244WMX	SOIC−20 WB, case 751D−05 (Pb−Free)	1000 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

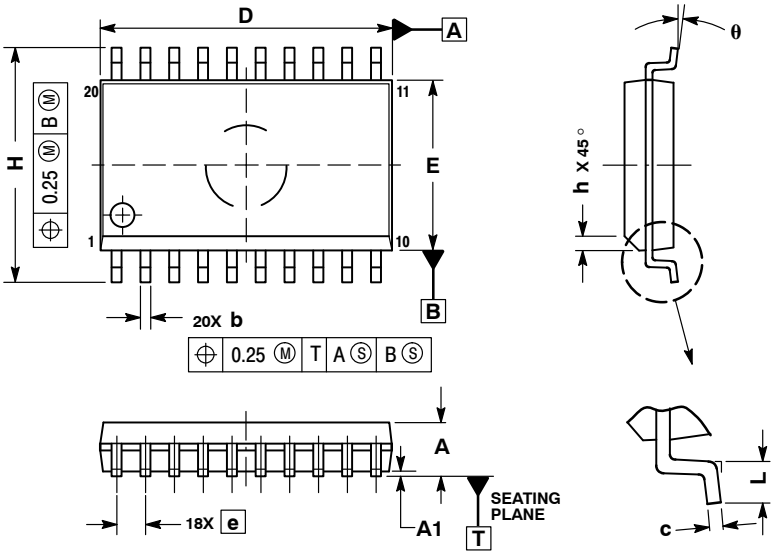
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS



SOIC−20 WB
CASE 751D−05
ISSUE H

DATE 22 APR 2015

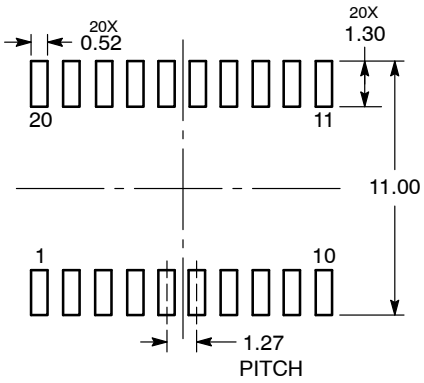
SCALE 1:1



NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS	
DIM	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

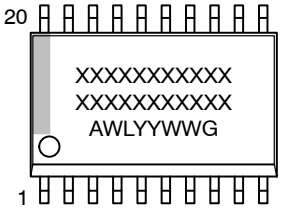
RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb−Free Package

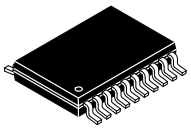
*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	**98ASB42343B**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.	
DESCRIPTION:	**SOIC−20 WB**		**PAGE 1 OF 1**

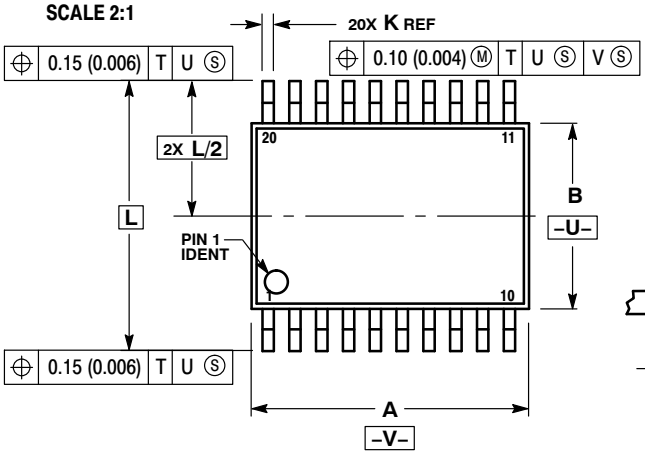
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

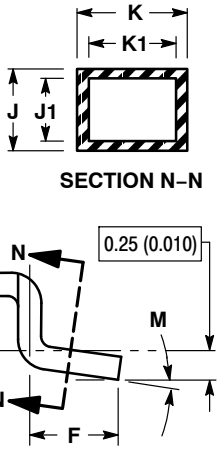
TSSOP−20 WB
CASE 948E
ISSUE D

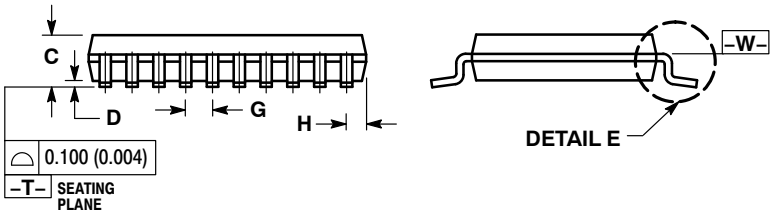
DATE 17 FEB 2016



SCALE 2:1



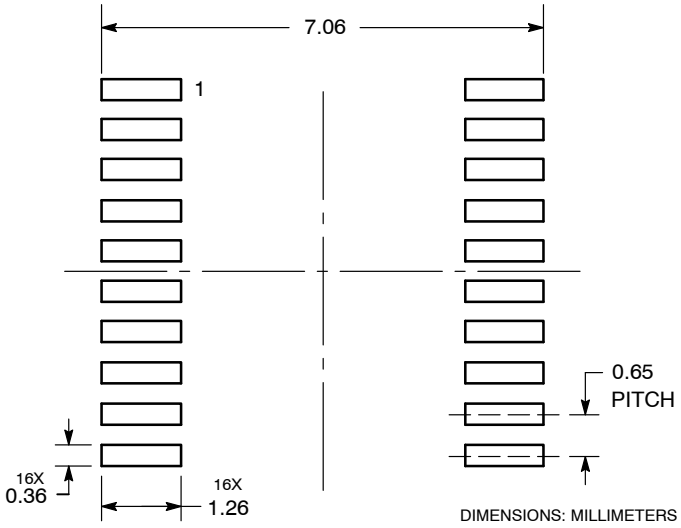




NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	6.40	6.60	0.252	0.260
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

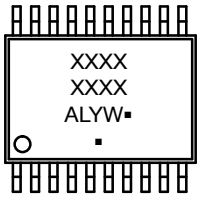
RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	**98ASH70169A**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.	
DESCRIPTION:	**TSSOP−20 WB**		**PAGE 1 OF 1**

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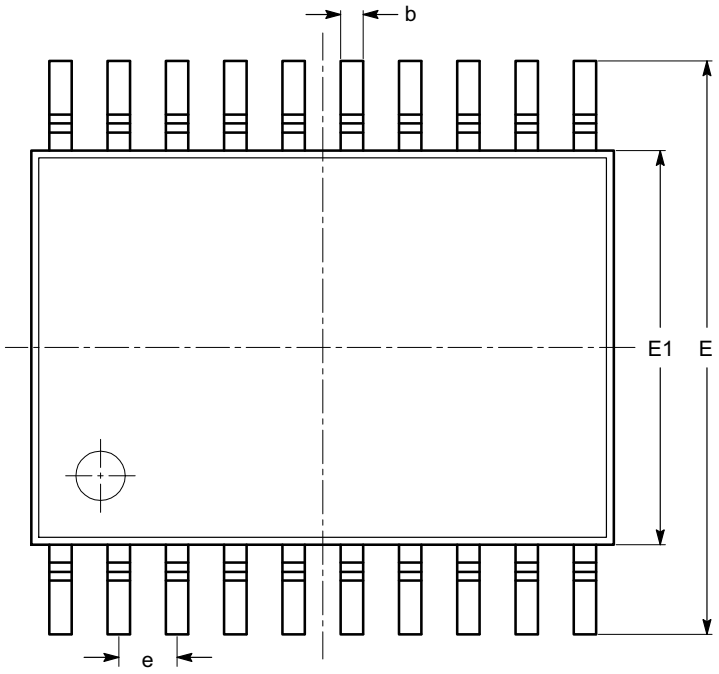
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

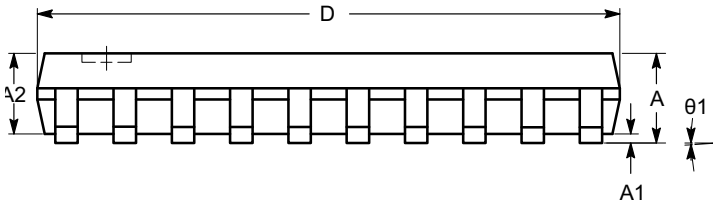
TSSOP20, 4.4x6.5
CASE 948AQ
ISSUE A

DATE 19 MAR 2009

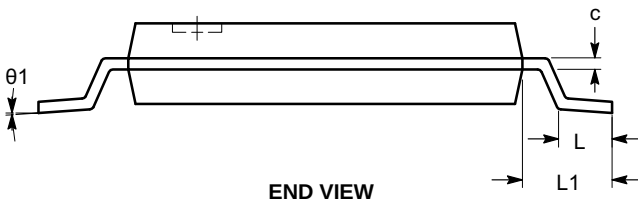


TOP VIEW

SYMBOL	MIN	NOM	MAX
A			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
c	0.09		0.20
D	6.40	6.50	6.60
E	6.30	6.40	6.50
E1	4.30	4.40	4.50
e		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°



SIDE VIEW



END VIEW

Notes:
(1) All dimensions are in millimeters. Angles in degrees.
(2) Complies with JEDEC MO-153.

DOCUMENT NUMBER:	**98AON34453E**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**TSSOP20, 4.4X6.5**	**PAGE 1 OF 1**

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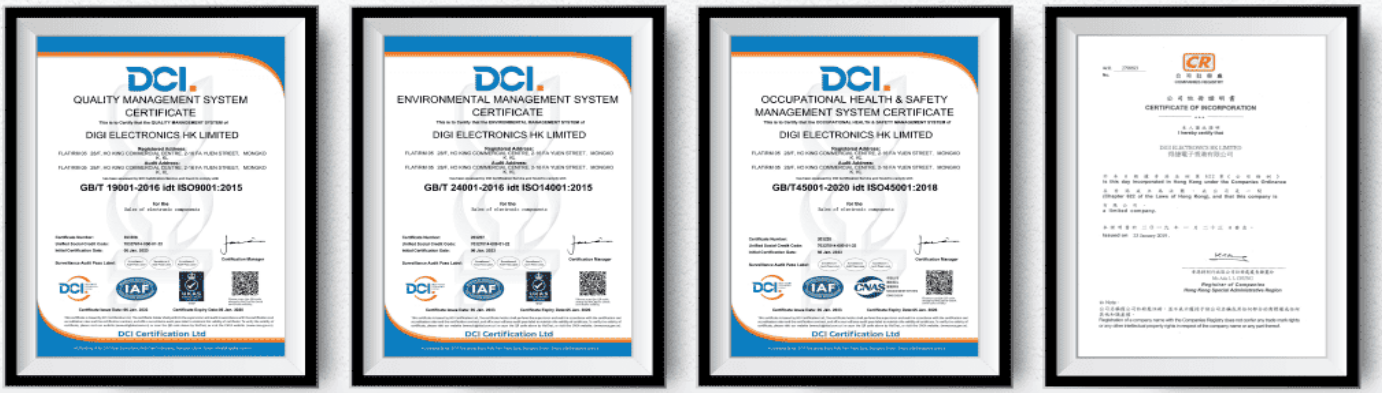

Tel: +00 852-30501935

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